

MX0912B351Y,114

MX0912B351Y,114 Information

bistor tra	MX0912B351Y,114 Ampleon USA Inc. Discrete Semiconductor Products Transistors - Bipolar (BJT) - RF TRANSISTOR POWER NPN SOT439A SOT-439A For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



MX0912B351Y,114 Specifications

Manufacturer Part Number	MX0912B351Y,114	
Manufacturer	Ampleon USA Inc.	
Category	Discrete Semiconductor Products	
	Transistors - Bipolar (BJT) - RF	
Package	SOT-439A	
Series	-	
Transistor Type	NPN	
Voltage - Collector Emitter Breakdown (Max)	20V	
Frequency - Transition	1.215GHz	
Noise Figure (dB Typ @ f)	-	
Gain	7.6dB	
Power - Max	960W	
DC Current Gain (hFE) (Min) @ Ic, Vce	-	
Current - Collector (Ic) (Max)	21A	
Operating Temperature	200°C (TJ)	
Mounting Type	Surface Mount	
Package / Case	SOT-439A	
Supplier Device Package	CDFM2	
	Report errors?	

MX0912B351Y,114 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE EUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

MX0912B351Y,114 Payment Methods



MX0912B351Y,114 Shipping Methods



If you have any question about MX0912B351Y,114, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com